NSN 5961-01-008-8910

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-008-8910 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 breakdown voltage, collector-to-base, emitter open **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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